# 3.3 V Dual Differential LVPECL/LVDS to LVTTL Translator

# Description

The MC100LVELT23 is a dual differential LVPECL/LVDS to LVTTL translator. Because LVPECL (Positive ECL) or LVDS levels are used only +3.3 V and ground are required. The small outline 8-lead package and the dual gate design of the LVELT23 makes it ideal for applications which require the translation of a clock and a data signal.

The LVELT23 is available in only the ECL 100K standard. Since there are no LVPECL outputs or an external  $V_{BB}$  reference, the LVELT23 does not require both ECL standard versions. The LVPECL inputs are differential. Therefore, the MC100LVELT23 can accept any standard differential LVPECL input referenced from a  $V_{CC}$  of +3.3 V.

## **Features**

- 2.0 ns Typical Propagation Delay
- Maximum Frequency > 180 MHz
- Differential LVPECL Inputs
- PECL Mode Operating Range: V<sub>CC</sub> = 3.0 V to 3.8 V with GND = 0 V
- 24 mA LVTTL Outputs
- Flow Through Pinouts
- Internal Pulldown and Pullup Resistors
- Pb-Free Packages are Available



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# MARKING DIAGRAMS\*



SOIC-8 D SUFFIX CASE 751





TSSOP-8 DT SUFFIX CASE 948R





1 4

DFN8 MN SUFFIX CASE 506AA

A = Assembly Location

L = Wafer Lot

Y = Year

W = Work Week

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)
\*For additional marking information, refer to
Application Note AND8002/D.

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

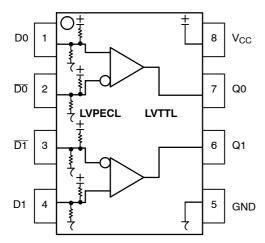


Figure 1. 8-Lead Pinout (Top View) and Logic Diagram

# **Table 1. PIN DESCRIPTION**

Pin	Function
Q0, Q1 D0*, D1* D0*, D1*	LVTTL Outputs Differential LVPECL Inputs
V <sub>CC</sub> GND EP	Positive Supply Ground (DFN8 only) Thermal exposed pad must be connected to a sufficient thermal con- duit. Electrically connect to the most neg- ative supply (GND) or leave unconnec- ted, floating open.

<sup>\*\*</sup> Pins will default to  $V_{\mbox{\footnotesize CC}}/2$  when left open.

# **Table 2. ATTRIBUTES**

Characteri	stics	Value							
Internal Input Pulldown Resistor		50 kΩ							
Internal Input Pullup Resistor		50 kΩ							
ESD Protection	Human Body Model Machine Model CDM	> 1500 V > 100 V > 2000 V							
Moisture Sensitivity, Indefinite Tim	e Out of Drypack (Note 1)	Level 1							
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in							
Transistor Count		91							
Meets or Exceeds JEDEC Spec E	Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test								

<sup>1.</sup> Refer to Application Note AND8003/D for additional information.

**Table 3. MAXIMUM RATINGS** 

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V <sub>CC</sub>	PECL Power Supply	GND = 0 V		3.8	V
VI	Input Voltage	GND = 0 V, V <sub>I</sub> not more positive than V <sub>CC</sub>		3.8	V
l <sub>out</sub>	Output Current	Continuous Surge		50 100	mA
T <sub>A</sub>	Operating Temperature Range			-40 to +85	°C
T <sub>stg</sub>	Storage Temperature			-65 to +150	°C
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient)	0 Ifpm 500 Ifpm	SOIC-8 SOIC-8	190 130	°C/W
θЈС	Thermal Resistance (Junction-to-Case)	Standard Board	SOIC-8	41 to 44 ± 5%	°C/W
$\theta_{\sf JA}$	Thermal Resistance (Junction-to-Ambient)	0 Ifpm 500 Ifpm	TSSOP-8 TSSOP-8	185 140	°C/W °C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	TSSOP-8	41 to 44 ± 5%	°C/W
$\theta_{JA}$	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	DFN8 DFN8	129 84	°C/W °C/W
T <sub>sol</sub>	Wave Solder Pb Pb-Free	<2 to 3 sec @ 248°C <2 to 3 sec @ 260°C		265 265	°C
θ <sub>JC</sub>	Thermal Resistance (Junction-to-Case)	(Note 2)	DFN8	35 to 40	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 4. LVPECL INPUT DC CHARACTERISTICS  $V_{CC}$  = 3.3 V; GND = 0 V (Note 3)

		-40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I <sub>CCH</sub>	Power Supply Current (Outputs set to HIGH)	10	20	35	10	20	35	10	20	35	mA
I <sub>CCL</sub>	Power Supply Current (Outputs set to LOW)	15	27	40	15	27	40	15	27	40	mA
V <sub>IH</sub>	Input HIGH Voltage (Note 5)	2135		2420	2135		2420	2135		2420	mV
V <sub>IL</sub>	Input LOW Voltage (Note 5)	1490		1825	1490		1825	1490		1825	mV
V <sub>IHCMR</sub>	Input HIGH Voltage Common Mode Range (Notes 4 and 5)	1.2		V <sub>CC</sub>	1.2		V <sub>CC</sub>	1.2		V <sub>CC</sub>	V
I <sub>IH</sub>	Input HIGH Current			150			150			150	μΑ
I <sub>IL</sub>	Input LOW Current D	-150			-150			-150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 3. All values vary 1:1 with  $V_{CC}$ .  $V_{CC}$  can vary  $\pm 0.3$  V. 4.  $V_{IHCMR}$  min varies 1:1 with GND, max varies 1:1 with  $V_{CC}$ .
- 5. LVTTL output  $R_L = 500 \Omega$  to GND.

<sup>2.</sup> JEDEC standard multilayer board - 2S2P (2 signal, 2 power)

Table 5. LVTTL OUTPUT DC CHARACTERISTICS V<sub>CC</sub> = 3.3 V; GND = 0V (Note 6)

		-40°C		25°C			85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V <sub>OH</sub>	Output HIGH Voltage (I <sub>OH</sub> = -3.0 mA) (Note 7)	2.4			2.4			2.4			V
V <sub>OL</sub>	Output LOW Voltage (I <sub>OL</sub> = 24 mA) (Note 7)			0.5			0.5			0.5	V
Ios	Output Short Circuit Current	-180		-50	-180		-50	-180		-50	mA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 6. All values vary 1:1 with  $V_{CC}.\ V_{CC}$  can vary  $\pm 0.3\ V.$
- 7. LVTTL output  $R_L$  = 500  $\Omega$  to GND.

Table 6. AC CHARACTERISTICS V<sub>CC</sub> = 3.3 V; GND = 0 V (Notes 8, 9)

			-40°C		25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
F <sub>max</sub>	Maximum Toggle Frequency (Note 10)	180			180			180			MHz
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay to Output Differential	1.0	1.5	2.5	1.0	1.7	2.5	1.0	1.7	2.5	ns
t <sub>SK++</sub> t <sub>SK</sub> t <sub>SKPP</sub>	Output-to-Output Skew++ Output-to-Output Skew Part-to-Part Skew (Note 11)		15 35 70	60 80 500		15 40 70	70 80 500		30 40 140	125 80 500	ps
t <sub>JITTER</sub>	Random Clock Jitter (RMS)		4.0	10		4.0	10		4.0	10	ps
V <sub>PP</sub>	Input Voltage Swing (Differential Configuration) (Note 12)	200	800	1000	200	800	1000	200	800	1000	mV
t <sub>r</sub> t <sub>f</sub>	Output Rise/Fall Times (0.8 V $-$ 2.0 V) Q, $\overline{\mathbb{Q}}$	330	600	900	330	600	900	330	650	900	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 8. All values vary 1:1 with V<sub>CC</sub>. V<sub>CC</sub> can vary  $\pm 0.3$  V. 9. LVTTL output R<sub>L</sub> = 500  $\Omega$  to GND and C<sub>L</sub> = 20 pF to GND. Refer to Figure 2.
- 10.  $F_{max}$  guaranteed for functionality only.  $V_{OL}$  and  $V_{OH}$  levels are guaranteed at DC only.
- 11. Skews are measured between outputs under identical conditions.
- 12.200 mV input guarantees full logic swing at the output.

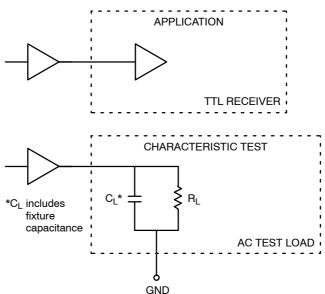


Figure 2. TTL Output Loading Used for Device Evaluation

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC100LVELT23D	SOIC-8	98 Units / Rail
MC100LVELT23DG	SOIC-8 (Pb-Free)	98 Units / Rail
MC100LVELT23DR2	SOIC-8	2500 / Tape & Reel
MC100LVELT23DR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC100LVELT23DT	TSSOP-8	100 Units / Rail
MC100LVELT23DTG	TSSOP-8 (Pb-Free)	100 Units / Rail
MC100LVELT23DTR2	TSSOP-8	2500 / Tape & Reel
MC100LVELT23DTRG	TSSOP-8 (Pb-Free)	2500 / Tape & Reel
MC100LVELT23MNRG	DFN8 (Pb-Free)	1000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **Resource Reference of Application Notes**

AN1405/D - ECL Clock Distribution Techniques

AN1406/D - Designing with PECL (ECL at +5.0 V)

AN1503/D - ECLinPS™ I/O SPiCE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family

AN1568/D - Interfacing Between LVDS and ECL

AN1672/D - The ECL Translator Guide

AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

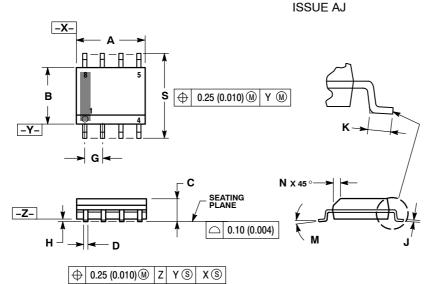
AND8020/D - Termination of ECL Logic Devices

AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices

#### **PACKAGE DIMENSIONS**

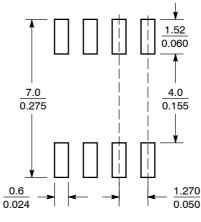
# SOIC-8 NB CASE 751-07



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PED SIDE
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
   DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
   751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27	BSC	0.05	0 BSC
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

## **SOLDERING FOOTPRINT\***

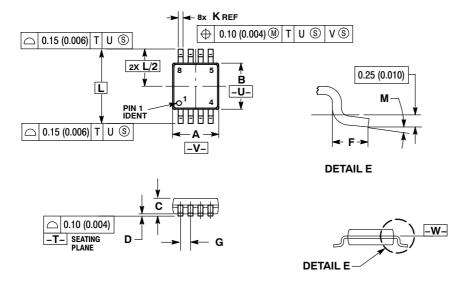


 $\left(\frac{\text{mm}}{\text{inches}}\right)$ SCALE 6:1

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**

# TSSOP-8 **DT SUFFIX** PLASTIC TSSOP PACKAGE CASE 948R-02 **ISSUE A**



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: MILLIMETER.

  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

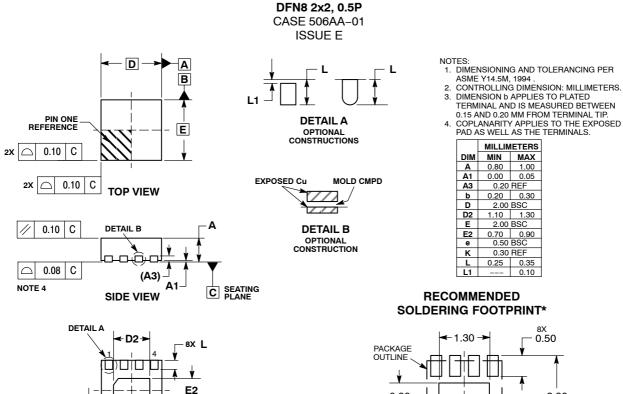
  4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

  5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

  6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE —W.

	MILLIN	INC	HES	
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
С	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65	BSC	0.026	BSC
K	0.25	0.40	0.010	0.016
L	4.90	BSC	0.193	BSC
М	0°	6 °	0°	6°

#### PACKAGE DIMENSIONS



CAB

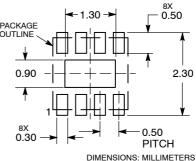
0.10

0.05 С NOTE 3 **MILLIMETERS** MIN MAX

0.80 1.00 0.00 0.05 0.20 REF 0.20 0.30 2.00 BSC 1.10 1.30 2.00 BSC 0.70 0.90 0.50 BSC 0.30 REF

0.35

#### **RECOMMENDED** SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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**BOTTOM VIEW** 

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